

# LL101A - LL101C

## SCHOTTKY BARRIER DIODES

### FEATURES :

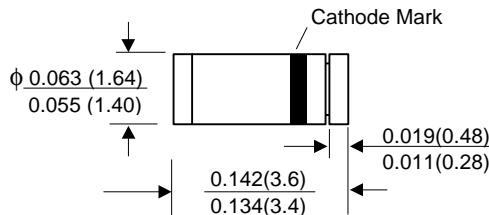
- For general purpose applications
- The LL101 series is a metal-on-silicon Schottky barrier device which is protected by a PN junction guard ring.
- The low forward voltage drop and fast switching make it ideal for protection of MOS devices, steering, biasing and coupling diodes for fast switching and low logic level applications.
- This diode is also available in the DO-35 case with type designation SD101A, B, C

### MECHANICAL DATA :

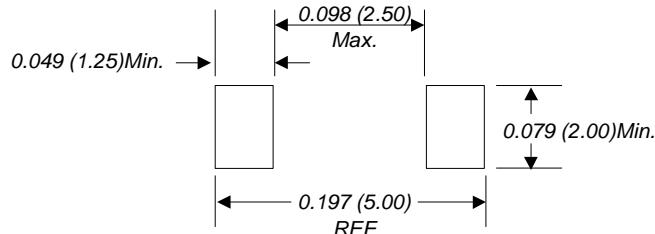
**Case:** MiniMELF Glass Case (SOD-80C)

**Weight:** approx. 0.05g

### MiniMELF (SOD-80C)



### Mounting Pad Layout



Dimensions in inches and ( millimeters )

### Maximum Ratings and Thermal Characteristics (Rating at 25 °C ambient temperature unless otherwise specified.)

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	60	V
LL101A		50	
LL101B		40	
LL101C			
Maximum Single Cycle Surge 10μs Square Wave	I <sub>FSM</sub>	2	A
Power Dissipation (Infinite Heatsink)	P <sub>D</sub>	400 <sup>(1)</sup>	mW
Thermal Resistance Junction to Ambient Air	R <sub>θJA</sub>	300 <sup>(1)</sup>	°C/W
Junction Temperature	T <sub>J</sub>	125 <sup>(1)</sup>	°C
Storage temperature range	T <sub>S</sub>	-55 to + 150 <sup>(1)</sup>	°C

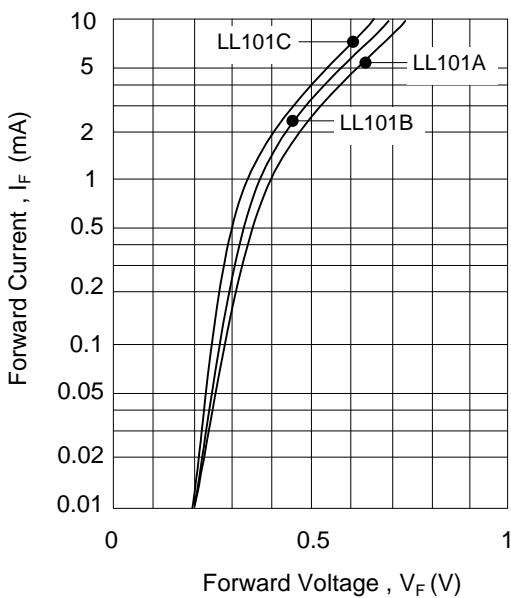
Note: (1) Valid provided that electrodes are kept at ambient temperature.

### Electrical Characteristics (T<sub>J</sub> = 25°C unless otherwise noted)

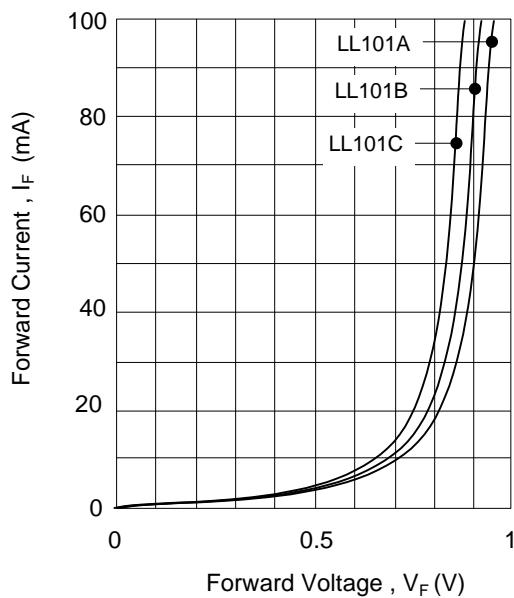
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Reverse Breakdown Voltage	V <sub>(BR)R</sub>	I <sub>R</sub> = 10 μA	60	-	-	V
LL101A			50	-	-	
LL101B			40	-	-	
LL101C						
Reverse Current	I <sub>R</sub>	V <sub>R</sub> = 50 V V <sub>R</sub> = 40 V V <sub>R</sub> = 30 V	-	-	200	nA
LL101A			-	-	200	
LL101B			-	-	200	
LL101C			-	-	200	
Forward Voltage Drop	V <sub>F</sub>	I <sub>F</sub> = 1mA	-	-	0.41	V
LL101A			-	-	0.4	
LL101B			-	-	0.39	
LL101C			-	-		
Forward Voltage Drop		I <sub>F</sub> = 15mA	-	-	1.0	
LL101A			-	-	0.95	
LL101B			-	-	0.9	
LL101C			-	-		
Reverse Recovery Time	T <sub>rr</sub>	I <sub>F</sub> = I <sub>R</sub> = 5mA , recover to 0.1I <sub>R</sub>	-	-	1	ns

## RATING AND CHARACTERISTIC CURVES ( LL101A - LL101C )

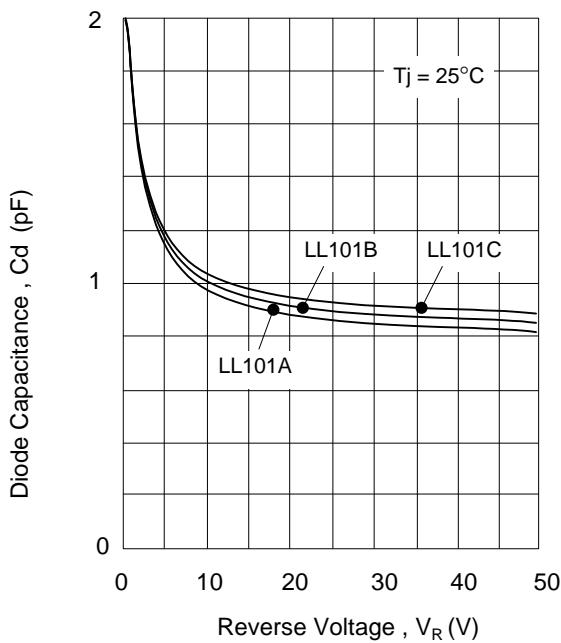
**Typical variation of forward current and forward voltage for primary conduction through the schottky barrier**



**Typical forward conduction curve of combination schottky barrier and PN junction guard ring**



**Typical capacitance curve as a function of reverse Voltage**



**Typical variation of reverse current at various temperatures**

